DISSIPATION: At ambient temperature of 25°C	75 max See curve p	mw age 68
AMBIENT-TEMPERATURE RANGE:	_	°C
Operating -65 to Storage -65 to	175	°Ğ
CASE TEMPERATURE:	275 max	°C
For 10 seconds maximum	210 max	
CHARACTERISTICS	•	
Static Values		
Peak-Point Current	50%	ma
Valley-Point Current:	0 70	Illa
Typical	2.5	ma
Maximum	3.5	ma
Peak-Point-to-Valley-Point Current Ratio:		
Minimum	13: 1	
Typical	20:1	
Peak-Point Voltage	260	rav
Valley-Point Voltage	1400	_ rav
Positive Voltage at peak-point ma = 52.51100 to	1400	1114
Dynamic Values		
Terminal Valley-Point Capacitance:*		
Typical. Maximum.	10	pf
Maximum	30	pf
Total Series Inductance	0.6 max	nh
Total Series Resistance	2.6 max	ohms
Negative Resistance of Intrinsic Diode	2.6	ohms
Dissipation at positive mv = 1400, peak-point ma = 52.5	73	naw
Rise Time for 20 per cent overdrive (dc forward voltage and driving pulse	0	2000
provided by constant-current sources)	2 max 0.9	ma/pf
Figure of Merit	0.9	ma/hr

^{*} At measured valley-point current of individual diode; includes case capacitance of 0.3 pf.



SILICON RECTIFIER

Hermetically sealed type used in power-supply applications at peak reverse voltages up to 200 volts. This type has a maximum average-forwardcurrent rating of 750 milliamperes for resistive or inductive loads and 500

1N3193

milliamperes for capacitive loads. It is designed to meet stringent temperature-cycling and humidity requirements of critical applications. Package is similar to JEDEC No. TO-1; outline 21, Outlines Section. This type is identical with type 1N3196 except for the following items:

MAXIMUM RATINGS

For power-supply frequency of 60 cps, single-phase operation

	Inductive Load	Load	
PEAK REVERSE VOLTAGE	$\begin{array}{c} 200\ max \\ 140\ max \end{array}$	$200 \ max \ 70 \ max$	volts volts
At ambient temperatures up to 75°C. PEAK RECURRENT CURRENT	750 max	500 max 6 max	ma amperes



SILICON RECTIFIER

Hermetically sealed type used in power-supply applications at peak reverse voltages up to 400 volts. This type has a maximum average-forwardcurrent rating of 750 milliamperes for resistive or inductive loads and 500

1N3194

milliamperes for capacitive loads. It is designed to meet stringent temperature-